

TOSHIBA Field Effect Transistor Silicon P/N Channel MOS Type(π-MOSVI)

SSM6L16FE

High Speed Switching Applications

Analog Switch Applications

- Small package
- Low on-resistance Q1: R_{DS(ON)} = 4 Ω (max) (@V_{GS} = 2.5 V)
 Q2: R_{DS(ON)} = 12 Ω (max) (@V_{GS} = -2.5 V)

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V _{DSS}	20	V
Gate-Source voltage		V _{GSS}	±10	V
Drain current	DC	I _D	100	mA
	Pulse	I _{DP}	200	

Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V _{DSS}	-20	V
Gate-Source voltage		V _{GSS}	±10	V
Drain current	DC	I _D	-100	mA
	Pulse	I _{DP}	-200	

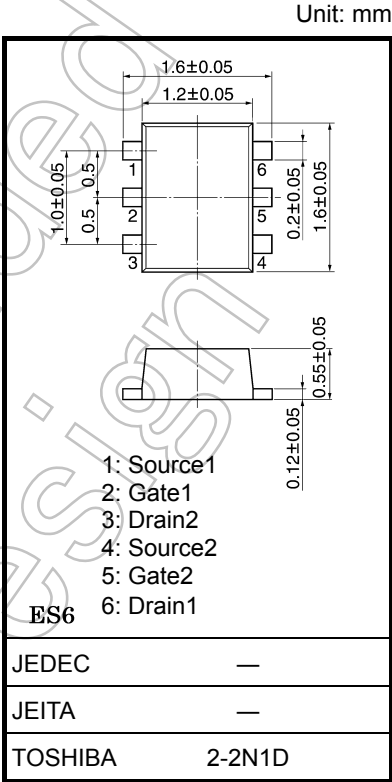
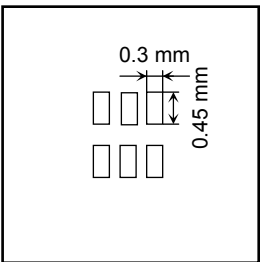
Absolute Maximum Ratings (Q1, Q2 Common)
(Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power dissipation	P _D (Note 1)	150	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

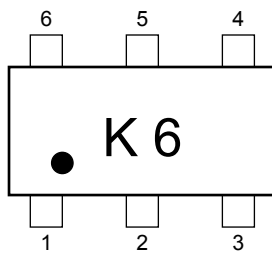
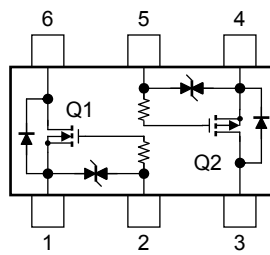
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating, mounted on FR4 board
(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 0.135 mm² × 6)



Weight: 3 mg (typ.)

Start of commercial production
2002-03

Marking**Equivalent Circuit (top view)****Handling Precaution**

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

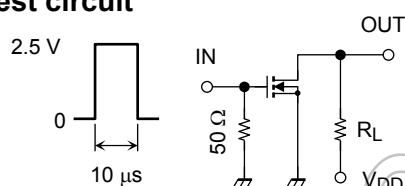
Q1 Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT
Gate leakage current		I_{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	—	—	± 1	μA
Drain-Source breakdown voltage		$V_{(BR) DSS}$	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	20	—	—	V
Drain cut-off current		I_{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0$	—	—	1	μA
Gate threshold voltage		V_{th}	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	0.6	—	1.1	V
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 3 \text{ V}, I_D = 10 \text{ mA}$ (Note2)	40	—	—	mS
Drain-Source on-resistance		$R_{DS(ON)}$	$I_D = 10 \text{ mA}, V_{GS} = 4 \text{ V}$ (Note2)	—	1.5	3.0	Ω
			$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$ (Note2)	—	2.2	4.0	
			$I_D = 1 \text{ mA}, V_{GS} = 1.5 \text{ V}$ (Note2)	—	5.2	15	
Input capacitance		C_{iss}	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	9.3	—	pF
Reverse transfer capacitance		C_{rss}		—	4.5	—	pF
Output capacitance		C_{oss}		—	9.8	—	pF
Switching time	Turn-on time	t_{on}	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA},$ $V_{GS} = 0 \text{ to } 2.5 \text{ V}$	—	70	—	ns
	Turn-off time	t_{off}		—	125	—	

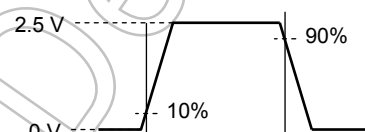
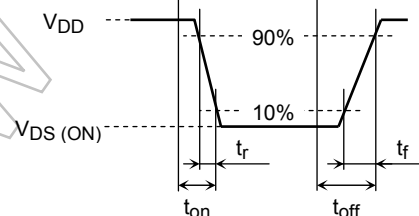
Note2: Pulse test

Switching Time Test Circuit

(a) Test circuit



$V_{DD} = 3 \text{ V}$
 Duty $\leq 1\%$
 V_{IN} : $t_r, t_f < 5 \text{ ns}$
 $(Z_{out} = 50 \Omega)$
 Common Source
 $T_a = 25^\circ\text{C}$

(b) V_{IN} (c) V_{OUT} 

Precaution

V_{th} can be expressed as the voltage between the gate and source when the low operating current value is $I_D = 0.1 \text{ mA}$ for this product. For normal switching operation, $V_{GS(on)}$ requires a higher voltage than V_{th} and $V_{GS(off)}$ requires a lower voltage than V_{th} . (The relationship can be established as follows: $V_{GS(off)} < V_{th} < V_{GS(on)}$.)

Be sure to take this into consideration when using the device.

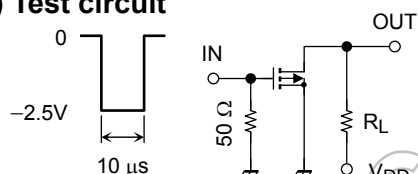
Q2 Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT
Gate leakage current		I_{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	—	—	± 1	μA
Drain-Source breakdown voltage		$V_{(BR) DSS}$	$I_D = -0.1 \text{ mA}, V_{GS} = 0$	-20	—	—	V
Drain cut-off current		I_{DSS}	$V_{DS} = -20 \text{ V}, V_{GS} = 0$	—	—	-1	μA
Gate threshold voltage		V_{th}	$V_{DS} = -3 \text{ V}, I_D = -0.1 \text{ mA}$	-0.6	—	-1.1	V
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = -3 \text{ V}, I_D = -10 \text{ mA}$ (Note3)	25	—	—	mS
Drain-Source on-resistance		$R_{DS(ON)}$	$I_D = -10 \text{ mA}, V_{GS} = -4 \text{ V}$ (Note3)	—	6	8	Ω
			$I_D = -10 \text{ mA}, V_{GS} = -2.5 \text{ V}$ (Note3)	—	8	12	
			$I_D = -1 \text{ mA}, V_{GS} = -1.5 \text{ V}$ (Note3)	—	18	45	
Input capacitance		C_{iss}	$V_{DS} = -3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	11	—	pF
Reverse transfer capacitance		C_{rss}		—	3.7	—	pF
Output capacitance		C_{oss}		—	10	—	pF
Switching time	Turn-on time	t_{on}	$V_{DD} = -3 \text{ V}, I_D = -10 \text{ mA},$ $V_{GS} = 0 \text{ to } -2.5 \text{ V}$	—	130	—	ns
	Turn-off time	t_{off}		—	190	—	

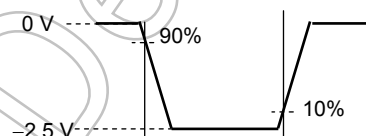
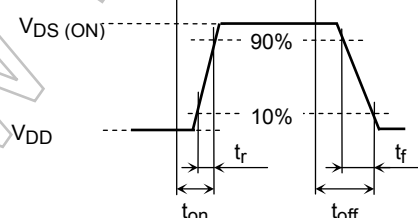
Note3: Pulse test

Switching Time Test Circuit

(a) Test circuit



$V_{DD} = -3 \text{ V}$
 Duty $\leq 1\%$
 V_{IN} : $t_r, t_f < 5 \text{ ns}$
 $(Z_{out} = 50 \Omega)$
 Common Source
 $T_a = 25^\circ\text{C}$

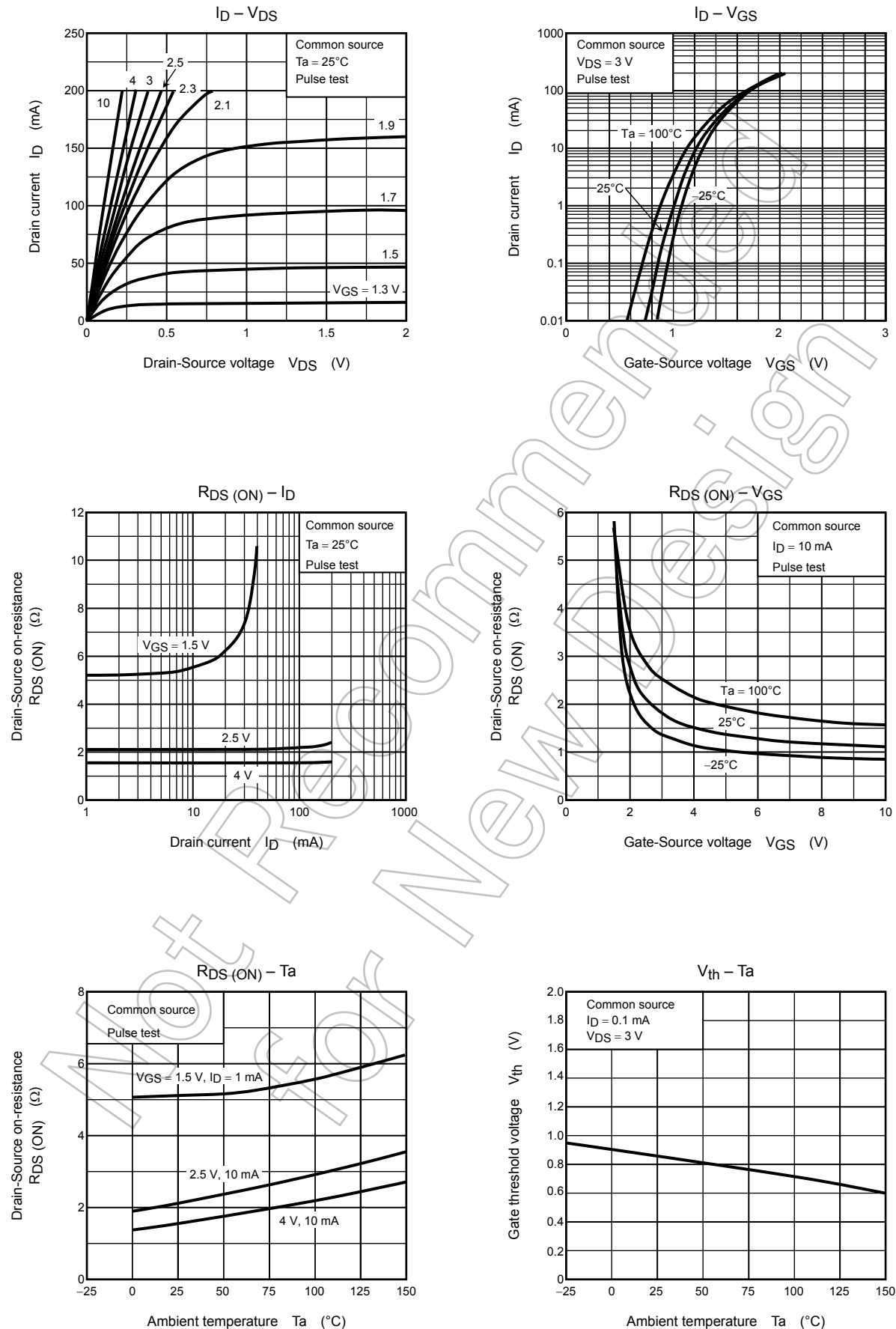
(b) V_{IN} (c) V_{OUT} 

Precaution

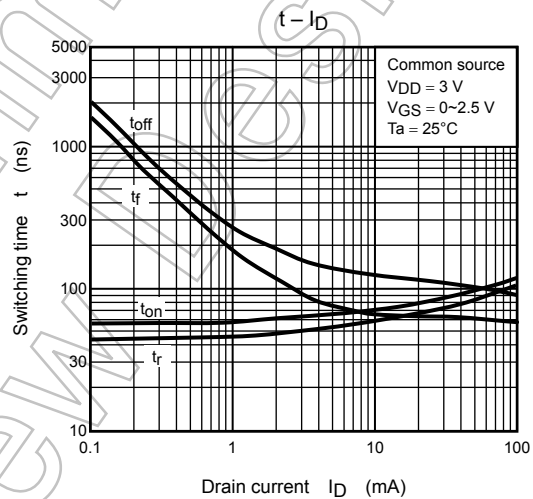
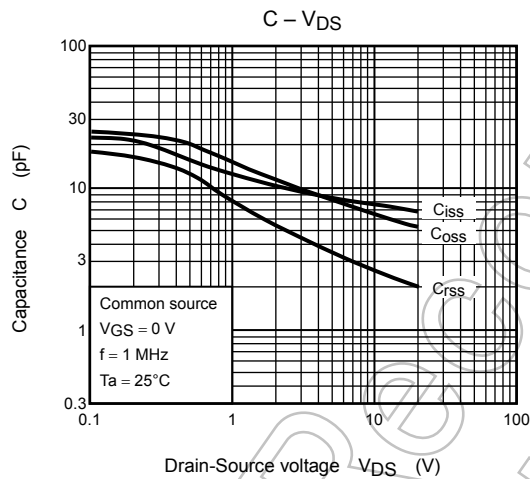
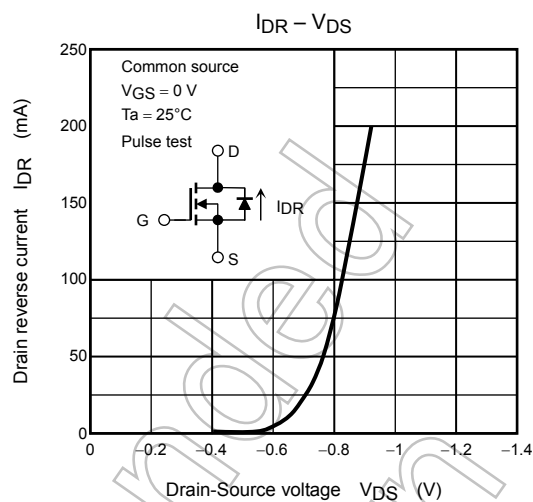
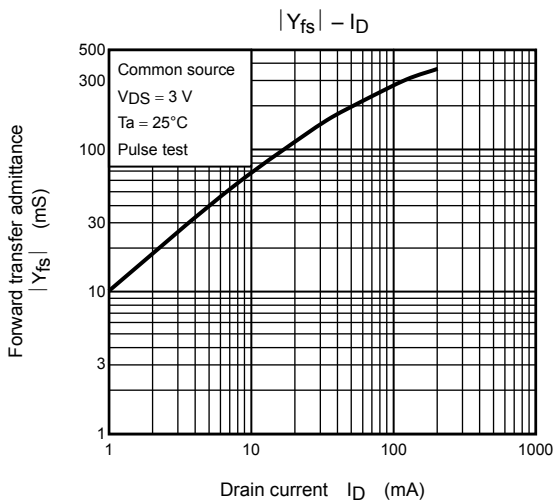
V_{th} can be expressed as the voltage between the gate and source when the low operating current value is $I_D = -0.1 \text{ mA}$ for this product. For normal switching operation, $V_{GS(on)}$ requires a higher voltage than V_{th} and $V_{GS(off)}$ requires a lower voltage than V_{th} . (The relationship can be established as follows: $V_{GS(off)} < V_{th} < V_{GS(on)}$.)

Be sure to take this into consideration when using the device.

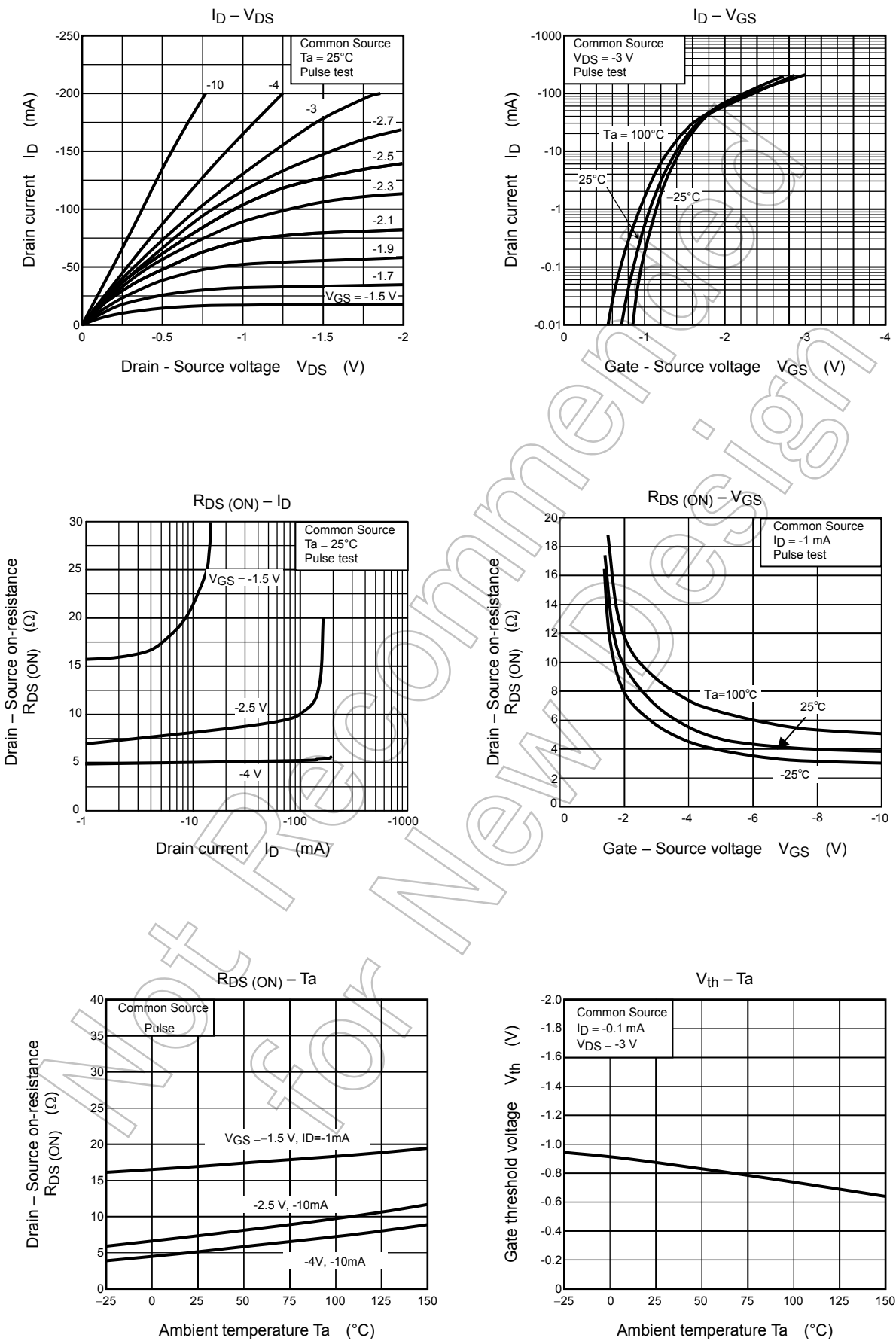
Q1 (N-ch MOSFET)



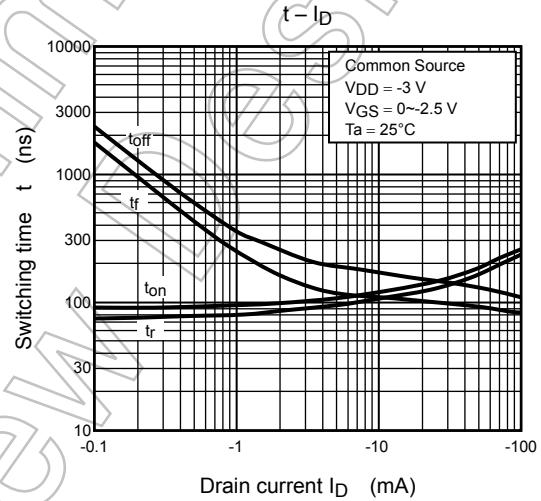
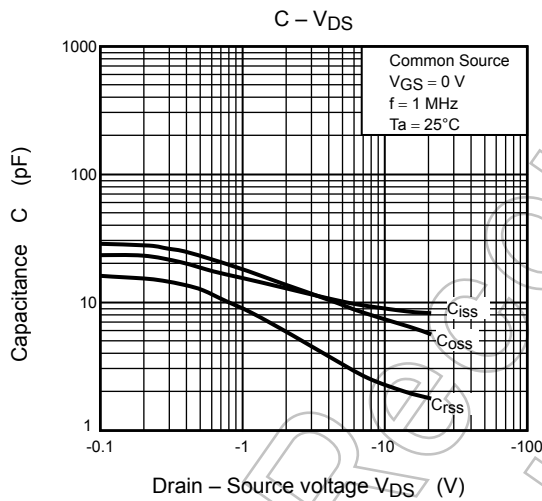
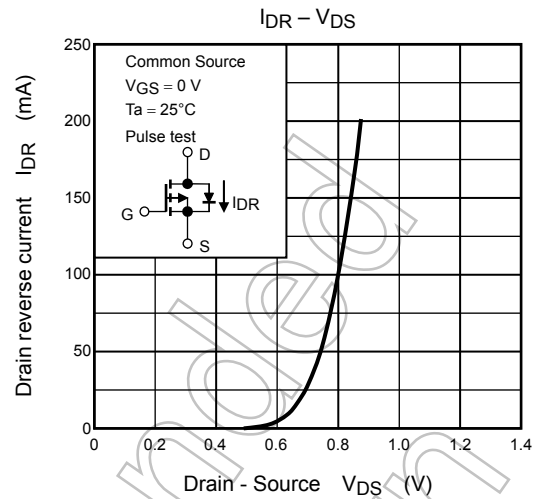
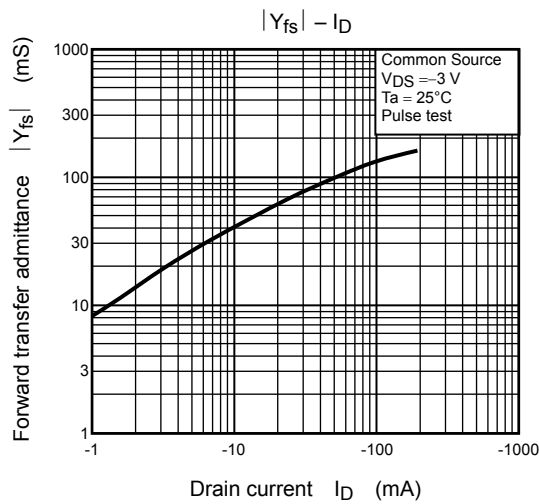
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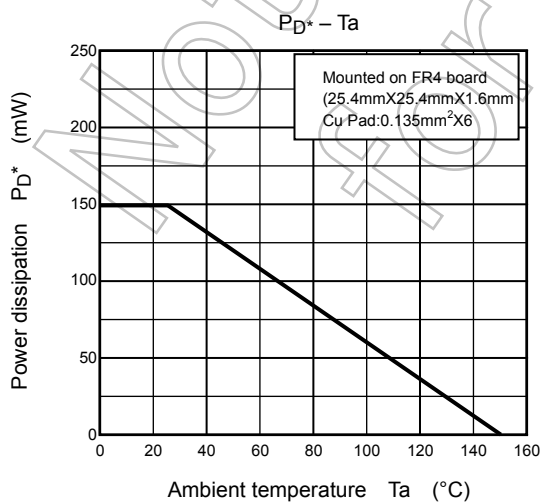
Q2 (P-ch MOSFET)



Q2 (P-ch MOSFET)



Common Characteristics



*: Total rating

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